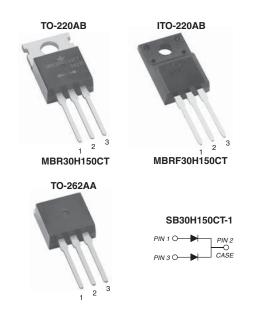


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Dual Common Cathode High Voltage Schottky Rectifier

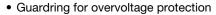
Low Leakage Current 5.0 µA



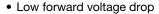
PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 15 A				
V _{RRM}	150 V				
I _{FSM}	260 A				
V _F	0.75 V				
T _J	175 °C				
Package	TO-220AB, ITO-220AB, TO-262AA				
Diode variations	Dual Common Cathode				

FEATURES

Power pack



· Low power losses, high efficiency



· High frequency operation

• Solder dip 275 °C max. 10 s, per JESD 22-B106

please see www.vishav.com/doc?99912

Solder dip 275 °C max. 10 s, per JESD 22-B106
Material categorization: For definitions of compliance

Pb

RoHS

TYPICAL APPLICATIONS

For use in high frequency inverters, freewheeling, and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

base 1711-Lo - Horio-compilant, commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PARAMETER		SYMBOL	MBR30H150CT	MBRF30H150CT	SB30H150CT-1	UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	150			V
Working peak reverse voltage		V_{RWM}	150			V
Maximum DC blocking voltage		V_{DC}	150			V
Maximum average forward rectified current	total device	I _{F(AV)}	30			А
	per diode			15		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	260		Α	
Peak repetitive reverse current per diode at t _p = 2 μs, 1 kHz		I _{RRM}		1.0		Α
Peak non-repetitive reverse surge energy per diode (8/20 µs waveform)		E _{RSM}		10		mJ
Non-repetitve avalanche energy per diode at 25 °C, I _{AS} = 2 A, L = 10 mH		E _{AS}		20		mJ
Voltage rate of change (rated V _R)		dV/dt		10 000		V/µs
Operating junction and storage temperature range		T _J , T _{STG}		- 65 to + 175		°C
Isolation voltage (ITO-220AB only) from terminals to heatsink t = 1 min		V _{AC}		1500		٧

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
Maximum instantaneous forward voltage per diode	V _F ⁽¹⁾	I _F = 15 A	T _C = 25 °C	0.90	V	
		I _F = 15 A	T _C = 125 °C	0.75		
		I _F = 30 A	T _C = 25 °C	0.99		
		I _F = 30 A	T _C = 125 °C	0.86		
Maximum reverse current per diode at working peak reverse voltage	I _R ⁽¹⁾		T _J = 25 °C	5.0	μΑ	
			T _J = 125 °C	1.0	mA	

Note

 $^{^{(1)}}$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT	
Typical thermal resistance per diode	$R_{\theta JC}$	1.7	4.0	1.7	°C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	MBR30H150CT-E3/45	2.06	45	50/tube	Tube	
ITO-220AB	MBRF30H150CT-E3/45	2.20	45	50/tube	Tube	
TO-262AA	SB30H150CT-1E3/45	1.58	45	50/tube	Tube	

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

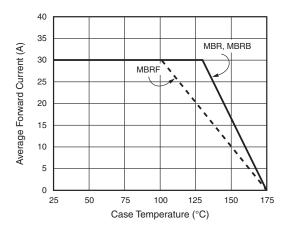


Fig. 1 - Forward Current Derating Curve (Total)

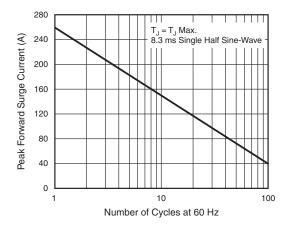


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode



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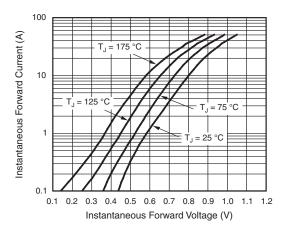


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

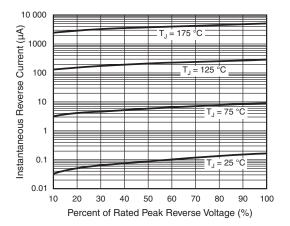
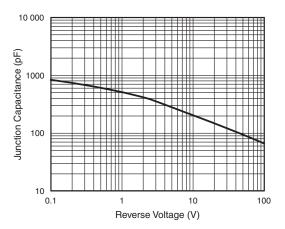


Fig. 4 - Typical Reverse Characteristics Per Diode



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Fig. 5 - Typical Junction Capacitance Per Diode

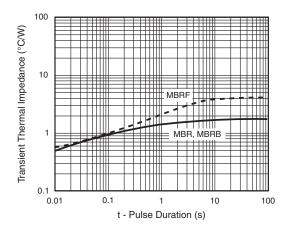


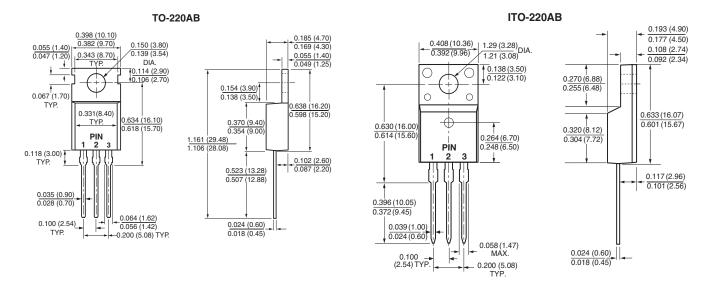
Fig. 6 - Typical Transient Thermal Impedance Per Diode



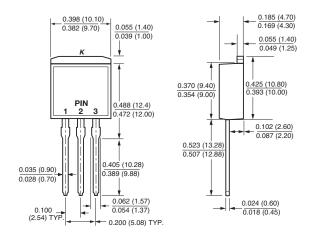
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-262AA





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